

FEATURES

- Quadrature VCO Outputs
- Wide Frequency Range (0.01Hz to 300kHz)
- Wide Supply Voltage Range (4.5V to 20V)
- TTL/HCMOS Compatible ($V_{CC} = 5VDC$)
- Wide Dynamic Range (2mV to 3Vrms)
- Adjustable Tracking Range ($\pm 1\%$ to $\pm 80\%$)
- Excellent Temp. Stability 20ppm/°C, Typ.

APPLICATIONS

- Frequency Synthesis
- Data Synchronization
- FM Detection
- Tracking Filters
- FSK Demodulation

GENERAL DESCRIPTION

The XR-2212 is an ultra-stable monolithic phase-locked loop (PLL) system especially designed for data communications and control system applications. Its on board reference and uncommitted operational amplifier, together with a typical temperature stability of better than 20ppm/°C, make it ideally suited for frequency synthesis,

FM detection, and tracking filter applications. The wide input dynamic range, large operating voltage range, large frequency range, and HCMOS and TTL compatibility contribute to the usefulness and wide applicability of this device.

ORDERING INFORMATION

Part No.	Package	Operating Temperature Range
XR-2212M	16 Lead 300 Mil CDIP	-55°C to +125°C
XR-2212CP	16 Lead 300 Mil PDIP	0°C to +70°C

BLOCK DIAGRAM

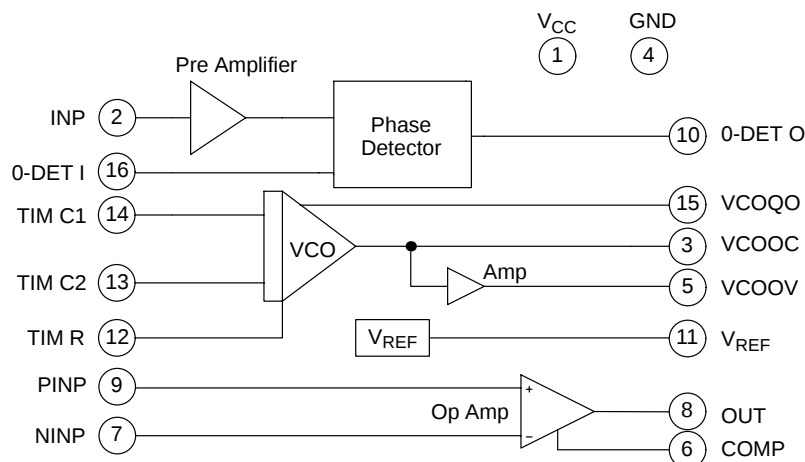
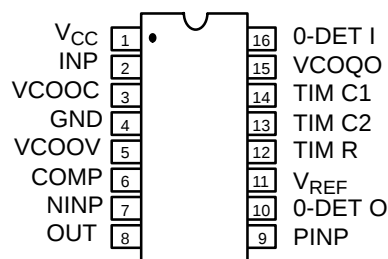


Figure 1. XR-2212 Block Diagram

PIN CONFIGURATION



16 Lead PDIP, CDIP (0.300")

PIN DESCRIPTION

Pin #	Symbol	Type	Description
1	V _{CC}		Positive Power Supply.
2	INP	I	Receive Analog Input.
3	VCOOC	O	VCO Current Output.
4	GND		Ground Pin.
5	VCOOV	O	VCO Voltage Source Output.
6	COMP	I	Uncommitted Amplifier, Frequency Compensation Input.
7	NINP	I	Inverted Input. Uncommitted amplifier.
8	OUT	O	Uncommitted Amplifier Output.
9	PINP	I	Positive Input. Uncommitted amplifier.
10	0-DET O	O	Phase Detector Output.
11	V _{REF}	O	Internal Voltage Reference. The value of V _{REF} is V _{CC} /2 -650mV.
12	TIM R	I	Timing Resistor Input. This pin connects to the timing resistor of the VCO.
13	TIM C2	I	Timing Capacitor Input. The timing capacitor connects between this pin and pin 14.
14	TIM C1	I	Timing Capacitor Input. The timing capacitor connects between this pin and pin 13.
15	VCOQO	O	VCO Quadrature Output.
16	0-DET I	I	Phase Detector Input.

ELECTRICAL CHARACTERISTICS

Test Conditions: $V_{CC} = +12V$, $T_A = +25^{\circ}C$, $R_0 = 30k\Omega$, $C_0 = 0.033\mu F$, unless otherwise specified. See *Figure 3* for component designation.

Parameter	XR-2212M			XR-2212CP			Units	Conditions	
	Min.	Typ.	Max.	Min.	Typ.	Max.			
General Characteristics									
Supply Voltage	4.5		15	4.5		15	V	R ₀ ≥ 10kΩ., See <i>Figure 5</i>	
Supply Current		6	10		6	12	mA		
Oscillator Section									
Frequency Accuracy	100	±1	±3		±1		%	Deviation from f ₀ = 1/R ₀ C ₀	
Frequency Stability								R ₁ = ∞	
Temperature		±20	±50		±20		ppm/°C	See <i>Figure 9</i>	
Power Supply		0.05	0.5		0.05		%/V	V _{CC} = 12 ± 1V, See <i>Figure 8</i>	
		0.2			0.2		%/V	V _{CC} = 5 ± 0.5V, See <i>Figure 8</i>	
Upper Frequency Limit		300			300		kHz	R ₀ = 8.2kΩ, C ₀ = 400pF	
Lowest Practical Operating Frequency			0.01		0.01		Hz	R ₀ = 2MΩ, C ₀ = 50μF	
Timing Resistor, R ₀									See <i>Figure 5</i>
Operating Range	5		2000	5		2000	kΩ	See <i>Figure 8</i> and <i>Figure 9</i>	
Recommended Range	15		100	15		100	kΩ		
Oscillator Outputs									
Voltage Output	100							Measured at Pin 5	
Positive Swing, V _{OH}		11			11		V		
Negative Swing, V _{OL}		0.4	0.8		0.5		V		
Current Sink Capability		1			1		mA	Measured at Pin 3	
Current Output									
Peak Current Swing		150			150		μA		
Output Impedance			1			1		MΩ	Measured at Pin 15
Quadrature Output									
Output Swing		0.6			0.6		V		
DC Level		0.3			0.3		V		
Output Impedance		3			3		kΩ	Referenced to Pin 11	
Loop Phase Detector Section								Measured at Pin 10	
Peak Output Current	±150	±200	±300	±100	±200	±300	μA	Referenced to Pin 11	
Output Offset Current		±1			±2		μA		
Output Impedance		1			1		MΩ		
Maximum Swing	±4	±5		±4	±5		V		

Note

Bold face parameters are covered by production test and guaranteed over operating temperature range.

ELECTRICAL CHARACTERISTICS (CONT'D)

Parameter	XR-2212M			XR-2212CP			Units	Conditions
	Min.	Typ.	Max.	Min.	Typ.	Max.		
Input Preamp Section								Measured at Pin 2
Input Impedance		20			20		kΩ	
Input Signal to Cause Limiting		2	10		2		mV rms	
Op Amp Section								
Voltage Gain	55	70		55	70		dB	R _L = 5.1kΩ, R _F = ∞
Input Bias Current		0.1	1		0.1	1	μA	
Offset Voltage		±5	±20		±5	±20	mV	
Slew Rate		2			2		V/μsec	
Internal Reference								Measured at Pin 11
Voltage Level	4.9	5.3	5.7	4.75	5.3	5.85	V	AC Small Signal
Output Impedance		100			100		Ω	
Maximum Source Current		80			80		ΩA	

Note

Bold face parameters are covered by production test and guaranteed over operating temperature range.

Specifications are subject to change without notice

ABSOLUTE MAXIMUM RATINGS

Power Supply 18V

Input Signal Level 3V rms

Power Dissipation:

Ceramic Package: 750mW

Derate Above $T_A = + 25^\circ C$ 6mW/ $^\circ C$

Plastic Package: 625mW

Derate Above $T_A = + 25^\circ C$ 5mW/ $^\circ C$

SYSTEM DESCRIPTION

The XR-2212 is a complete PLL system with buffered inputs and outputs, an internal reference, and an uncommitted op amp. Two VCO outputs are pinned out; one sources current, the other sources voltage. This enables operation as a frequency synthesizer using an external programmable divider. The op amp section can be used as an audio preamplifier for FM detection or as a high speed sense amplifier (comparator) for FSK demodulation. The center frequency, bandwidth, and tracking range of the PLL are controlled independently by

external components. The PLL output is directly compatible with CMOS, HCMOS and TTL logic families as well as microprocessor peripheral systems.

The precision PLL system operates over a supply voltage range of 4.5V to 20V, a frequency range of 0.01Hz to 300kHz, and accepts input signals in the range of 2mV to 3V rms. Temperature stability of the VCO is typically better than 20 ppm/ $^\circ C$ with the optimum timing resistor value.



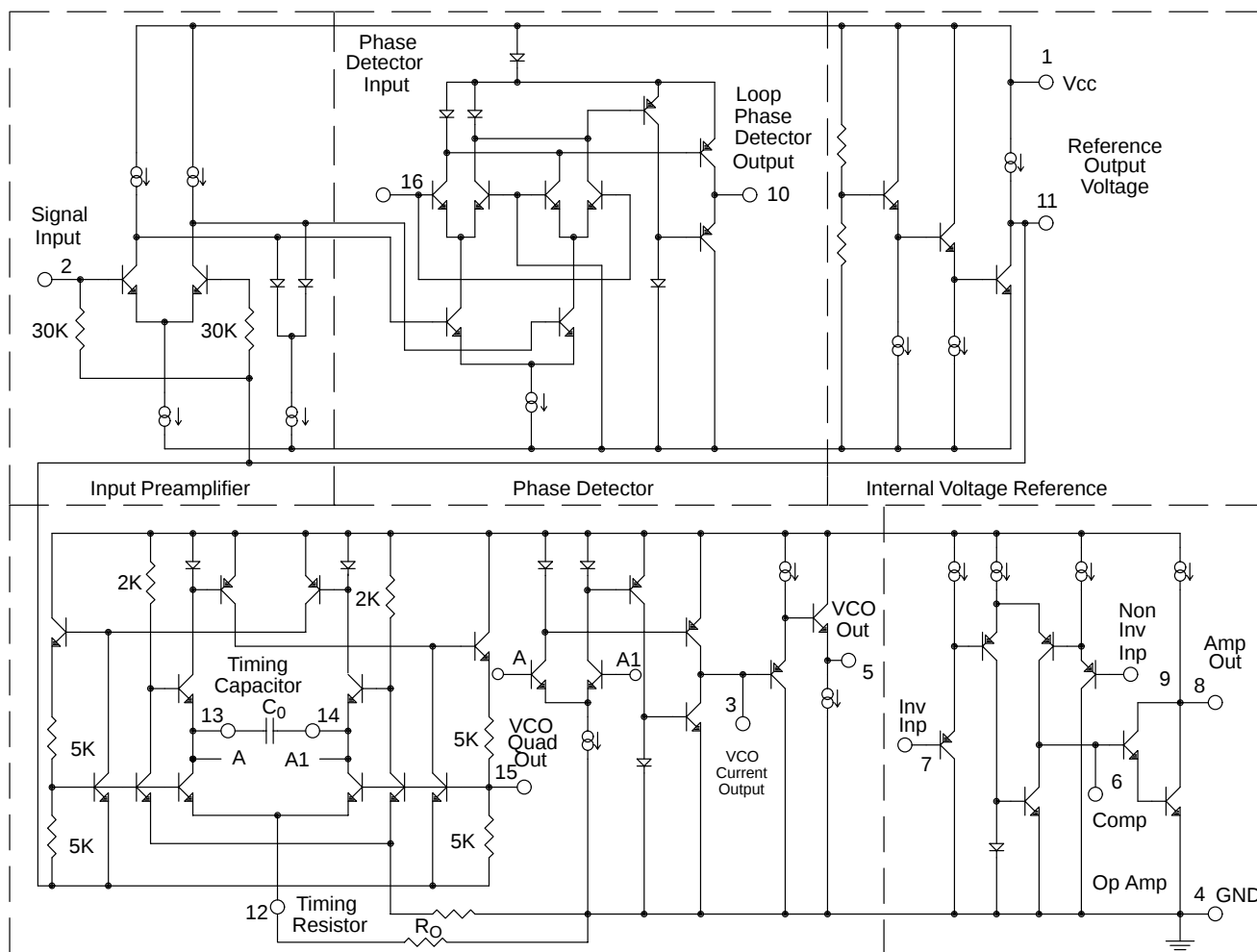


Figure 4. Simplified Circuit Schematic of XR-2212

TYPICAL CHARACTERISTICS

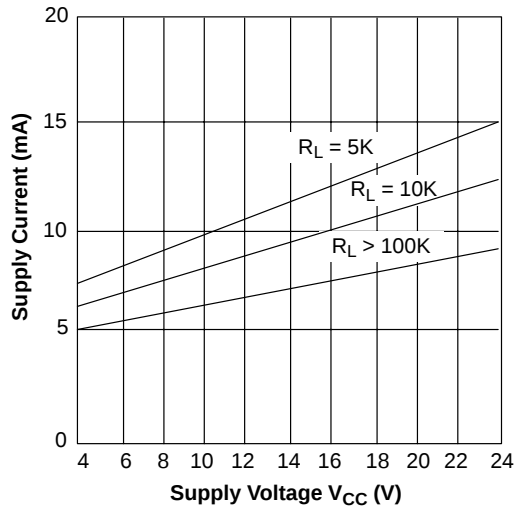


Figure 5. Typical Supply Current vs. V_{CC} (Logic Outputs Open Circuited)

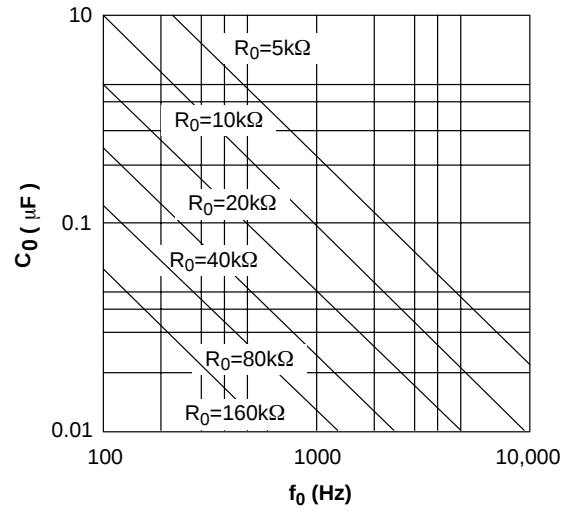


Figure 6. VCO Frequency vs. Timing Resistor

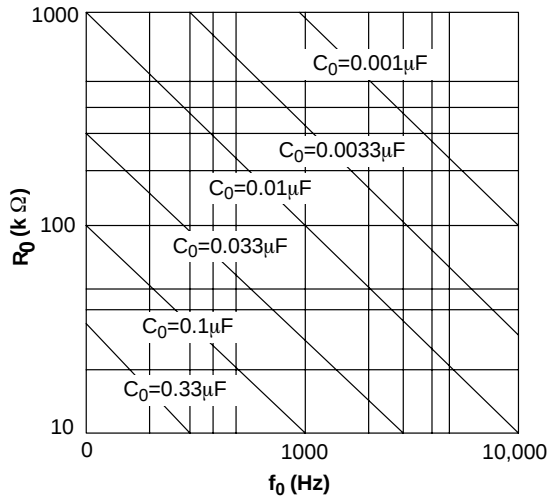


Figure 7. VCO Frequency vs. Timing Capacitor

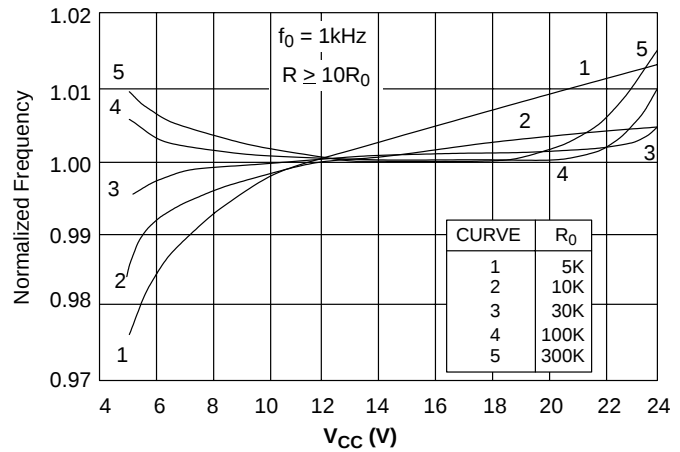


Figure 8. Typical f_0 vs. Power Supply Characteristics

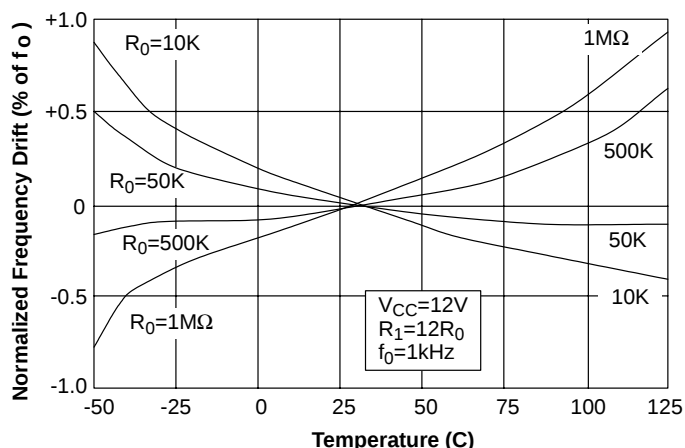


Figure 9. Typical Center Frequency Drift vs. Temperature

DESCRIPTION OF CIRCUIT CONTROLS

Signal Input (Pin 2): Signal is AC coupled to this terminal. The internal impedance at Pin 2 is 20k Ω . Recommended input signal level is in the range of 10mV to 5V peak-to-peak.

VCO Current Output (Pin 3): This is a high impedance (M Ω) current output terminal which can provide $\pm 100\mu\text{A}$ drive capability with a voltage swing equal to V_{CC} . This output can directly interface with CMOS or NMOS logic families.

VCO Voltage Output (Pin 5): This terminal provides a low- impedance ($\approx 50\Omega$) buffered output for the VCO. It can directly interface with low-power Schottley TTL. For interfacing with standard TTL circuits, a 750 Ω pull-down resistor from Pin 5 to ground is required. For operation of the PLL without an external divider, Pin 5 can be DC coupled to Pin 16.

Op Amp Compensation (Pin 6): The op amp section is frequency compensated by connecting an external capacitor from Pin 6 to the amplifier output (Pin 8). For unity-gain compensation a 20pF capacitor is recommended.

Op Amp Inputs (Pins 7 and 9): These are the inverting and the non-inverting inputs for the op amp section. The common-mode range of the op amp inputs is from +1V to ($V_{CC} - 1.5$) volts.

Op Amp Output (Pin 8): The op amp output is an open-collector type gain stage and requires a pull-up resistor, R_L , to V_{CC} for proper operation. For most applications, the recommended value of R_L is in 5k Ω to 10k Ω range.

Phase Detector Output (Pin 10): This terminal provides a high-impedance output for the loop phase-detector. The PLL loop filter is formed by R_1 and C_1 connected to Pin 10 (see Figure 3). With no input signal, or with no phase-error within the PLL, the DC level at Pin 10 is very nearly equal to V_{REF} . The peak voltage swing available at the phase detector output is equal to $\pm V_{REF}$.

Reference Voltage, V_{REF} (Pin 11): This pin is internally biased at the reference voltage level. $V_{REF}: V_{REF} = V_{CC}/2 - 650\text{mV}$. The DC voltage level at this pin forms an internal reference for the voltage levels at Pins 10, 12 and 16. Pin 1 must be bypassed to ground with a 0.1 μF capacitor, for proper operation of the circuit.

VCO Control Input (Pin 12): VCO free-running frequencies determined by external timing resistor, R_0 , connected from this terminal to ground. For optimum temperature stability, R_0 must be in the range of 10k Ω to 100k Ω (see Figure 9).

VCO Frequency Adjustment: VCO can be fine-tuned by connecting a potentiometer, R_X , in series with R_0 at Pin 12 (see Figure 11).

This terminal is a low-impedance point, and is internally biased at a DC level equal to V_{REF} . The maximum timing

current drawn from Pin 12 must be limited to ≤ 3 mA for proper operation of the circuit.

VCO Timing Capacitor (Pins 13 and 14): VCO frequency is inversely proportional to the external timing capacitor, C_0 , connected across these terminals (see *Figure 6*). C_0 must be nonpolar, and in the range of 200pF to 10 μ F.

VCO Quadrature Output (Pin 15): The low-level (≈ 0.6 Vpp) output at this pin is at quadrature phase (i.e. 90° phase-offset) with the other VCO outputs at Pins 3 and 5. The DC level at Pin 15 is approximately 300mV above V_{REF} . The quadrature output can be used with an external multiplier as a “lock detect” circuit. In order not to degrade oscillator performance, the output at Pin 15 must be buffered with an external high impedance low capacitance amplifier. When not in use, Pin 15 should be left open-circuited.

Phase Detector Input (Pin 16): Voltage output of the VCO (Pin 5) or the output of an external frequency divider

is connected to this pin. The DC level of the sensing threshold for the phase detector is referenced to V_{REF} . If the signal is capacitively coupled to Pin 16, then this pin must be biased from Pin 11, through an external resistor, R_B ($R_B \approx 10k\Omega$). The peak voltage swing applied to Pin 16 must not exceed ($V_{CC} - 1.5$) volts.

PHASE-LOCKED LOOP PARAMETERS

Transfer Characteristics

Figure 10 shows the basic frequency to voltage characteristics of XR-2212. With no input signal present, filtered phase detector output voltage is approximately equal to the internal reference voltage, V_{REF} at Pin 11. The PLL can track an input signal over its tracking bandwidth, shown in the figure. The frequencies f_{TL} and f_{TH} represent the lower and the upper edge of the tracking range, f_0 represents the VCO center frequency.

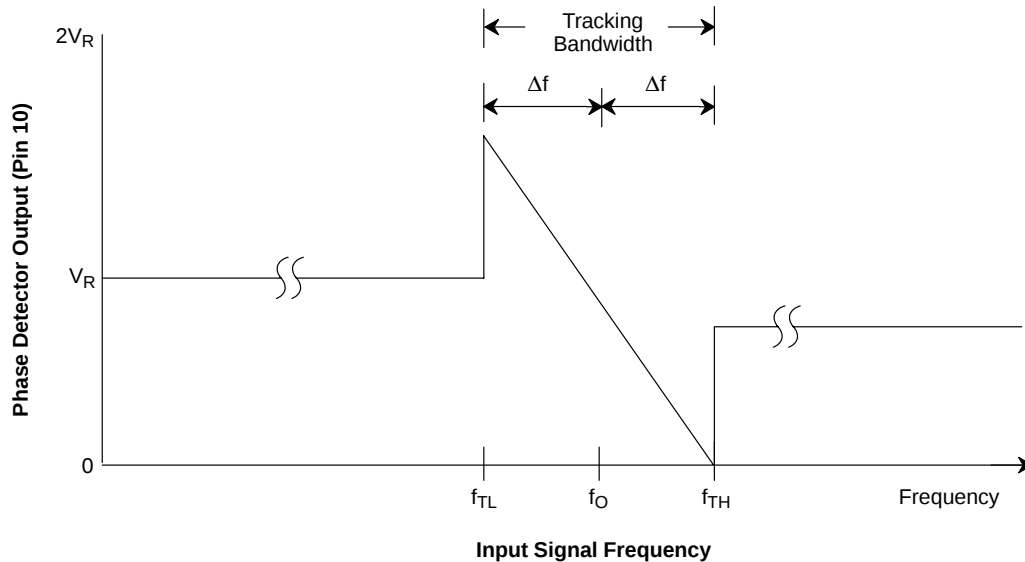


Figure 10. Phase Detector Output Voltage (Pin 10) as a Function of Input Signal Frequency

Note

Output Voltage is Referenced to Internal Reference Voltage V_{REF} at Pin 11

Design Equations

(See *Figure 3* and *Figure 10* for definition of components.)

1. VCO Center Frequency, f_0 : $f_0 = 1/R_0C_0$ Hz
2. Internal Reference Voltage, V_{REF} (measured at Pin 11)
 $V_{REF} = V_{CC}/2 - 650\text{mV}$
3. Loop Low-Pass Filter Time Constant, τ : $\tau = R_1C_1$
4. Loop Damping, ζ :

$$\zeta = 0.25 \sqrt{\frac{NC_0}{C_1}}$$

where N is the external frequency divider modular (See 2). If no divider is used, $N = 1$.

5. Loop Tracking Bandwidth, $\pm \Delta f/f_0$: $\Delta f/f_0 = R_0/R_1$
6. Phase Detector Conversion Gain, K_ϕ : (K_ϕ is the differential DC voltage across Pins 10 and 11, per unit of phase error at phase-detector input)
 $K_\phi = -2V_{REF}/\pi$ volts/radian
7. VCO Conversion Gain, K_0 : (K_0 is the amount of change in VCO frequency, per unit of DC voltage change at Pin 10. It is the reciprocal of the slope of conversion characteristics shown in *Figure 10*).
 $K_0 = -1/V_{REF}C_0R_1$ Hz/V

8. Total Loop Gain, K_T
 $K_T = 2\pi K_\phi K_0 = 4/C_0R_1$ rad/sec/volt
9. Peak Phase-Detector Current, I_A ; available at Pin 10.
 $I_A = V_{REF}(\text{volts})/25\text{mA}$

APPLICATION INFORMATION

FM Demodulation

XR-2212 can be used as a linear FM demodulator for both narrow-band and wide-band FM signals. The generalized circuit connection for this application is shown in *Figure 11*, where the VCO output (Pin 5) is directly connected to the phase detector input (Pin 16). The demodulated signal is obtained at phase detector output (Pin 10). In the circuit connection of *Figure 10*, the op amp section of XR-2212 is used as a buffer amplifier to provide both additional voltage amplification as well as current drive capability. Thus, the demodulated output signal available at the op amp output (Pin 8) is fully buffered from the rest of the circuit.

In the circuit of *Figure 11*, R_0C_0 set the VCO center frequency, R_1 sets the tracking bandwidth, C_1 sets the low-pass filter time constant. Op amp feedback resistors R_F and R_C set the voltage gain of the amplifier section.

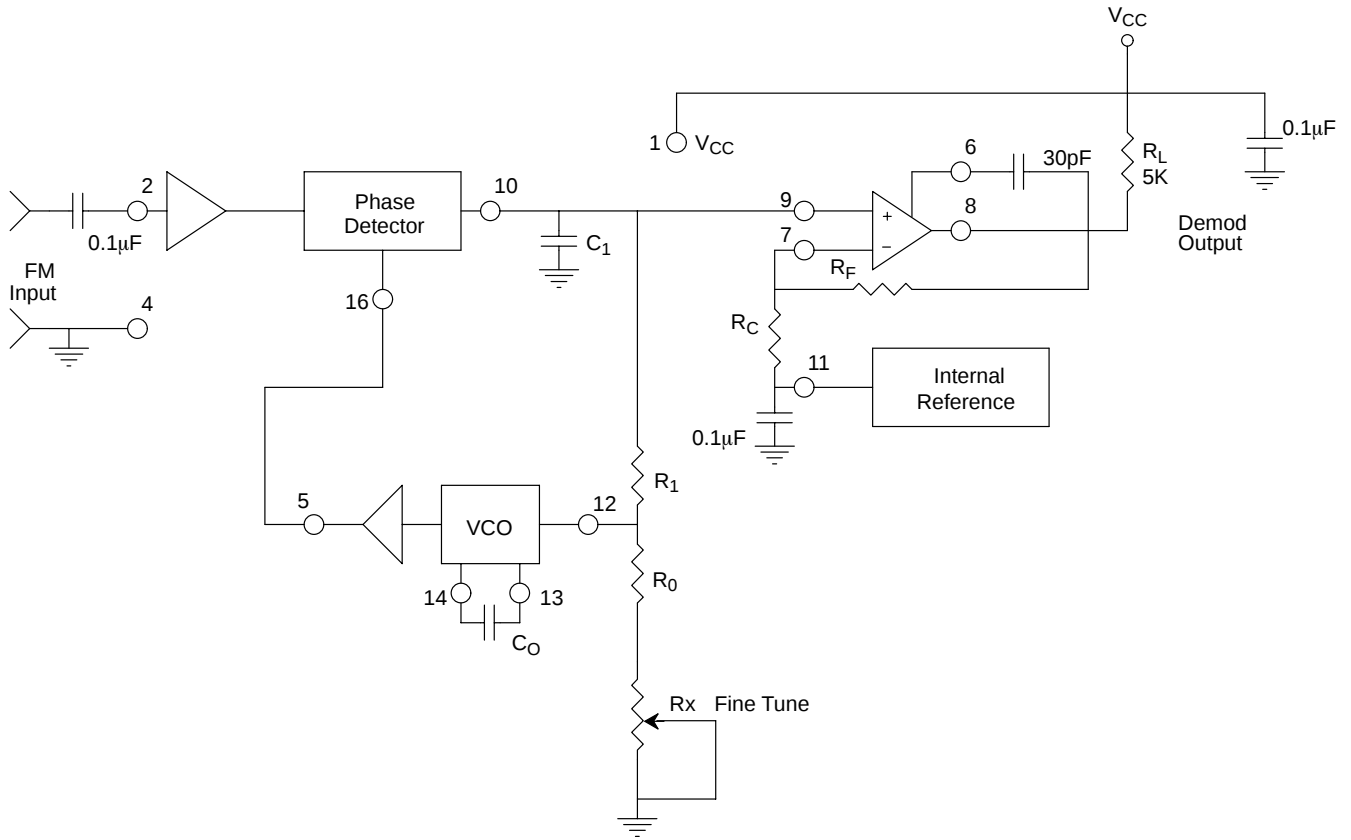


Figure 11. Circuit Connection for FM Demodulation

Design Instructions

The circuit of *Figure 11* can be tailored to any FM demodulation application by a choice of the external components R_0 , R_1 , R_C , R_F , C_0 and C_1 . For a given FM center frequency and frequency deviation, the choice of these components can be calculated as follows, using the design equations and definitions given on page 10.

- Choose VCO center frequency f_0 to be the same as FM carrier frequency.
- Choose value of timing resistor R_0 , to be in the range of 10k Ω to 100k Ω . This choice is arbitrary. The recommended value is $R_0 = \sim 20\text{k}\Omega$. The final value of R_0 is normally fine-tuned with the series potentiometer, R_X .
- Calculate value of C_0 from design equation (1) or from *Figure 7*:

$$C_0 = 1/R_0 f_0$$

- Choose R_1 to determine the tracking bandwidth, Δf (see design equation 5). The tracking bandwidth, Δf , should be set significantly wider than the maximum input FM signal deviation, Δf_{SM} . Assuming the tracking bandwidth to be "N" times larger than Δf_{SM} , one can re-unite design equation 5 as:

$$\frac{\Delta f}{f_0} = \frac{R_0}{R_1} = N \frac{\Delta f_{SM}}{f_0}$$

Table 2. lists recommended values of N, for various values of the maximum deviation of the input FM signal.

- Calculate C_1 to set loop damping (see design equation 4). Normally, $\zeta = 1/2$ is recommended. Then, $C_1 = C_0/4$ for $\zeta = 1/2$.

% Deviation of FM Signal ($\Delta f_{SM}/f_0$)	Recommended Value of Bandwidth Ratio, N ($N = \Delta f/\Delta f_{SM}$)
1% or less	10
1% to 3%	5
1% to 5%	4
5% to 10%	3
10% to 30%	2
30% to 50%	1.5

Table 2.

Recommended values of bandwidth ratio, N, for various values of FM signal frequency deviation. (Note: N is the ratio of tracking bandwidth Δf to max. signal frequency deviation, Δf_{SM}).

- f) Calculate R_C and R_F to set peak output signal amplitude. Output signal amplitude, V_{OUT} , is given as:

$$V_{OUT} = \left(\frac{\Delta f_{SM}}{f_0} \right) (V_{REF}) \left(\frac{R_1}{R_0} \right) \left(\frac{R_C + R_F}{R_C} \right)$$

In most applications, $R_F = 100k\Omega$ is recommended; then R_C , can be calculated from the above equation to give desired output swing. The output amplifier can also be used as a unity-gain voltage follower, by open circuiting R_C (i.e., $R_C = \infty$).

Note: All calculated component values except R_0 can be rounded-off to the nearest standard value, and R_0 can be varied to fine-tune center frequency, through a series potentiometer, R_X , (See Figure 11).

Design Example

Demodulator for FM signal with 67kHz carrier frequency with $\pm 5kHz$ frequency deviation. Supply voltage is +12V and required peak output swing is $\pm 4V$.

- Step a) f_0 is chosen as 67kHz.
- Step b) Choose $R_0 = 20k\Omega$ (18k Ω fixed resistor in series with 5k Ω potentiometer).
- Step c) Calculate C_0 ; from design equation (1).
 $C_0 = 746pF$
- Step d) Calculate R_1 . For given FM deviation, $\Delta f_{SM}/f_0 = 0.0746$, and $N = 3$ from Table 2. Then:

$$R_0/R_1 = (3)(0.0746) = 0.224$$

or:

$$R_1 = 89.3k\Omega.$$

Step e): Calculate $C_1 = (C_0/4) = 186pF$.

Step f): Calculate R_C and R_F to get $\pm 4V$ peak output swing: Let $R_F = 100k\Omega$. Then,

$$R_C = 80.6k\Omega.$$

Note: All values except R_0 can be rounded-off to nearest standard value.

FREQUENCY SYNTHESIS

Figure 12 shows the generalized circuit connection for frequency synthesis. In this application an external frequency divider is connected between the VCO output (Pin 5) and the phase-detector input (Pin 16). When the circuit is in lock, the two signals going into the phase-detector are at the same frequency, or $f_S = f_1/N$ where N is the modulus of the external frequency divider. Conversely, the VCO output frequency, f_1 is equal to Nf_S .

In the circuit configuration of Figure 12, the external timing components, R_0 and C_0 , set the VCO free running frequency; R_1 sets the tracking bandwidth and C_1 sets the loop damping, i.e., the low-pass filter time constant (see design equations).

The total tracking range of the PLL (see Figure 10), should be chosen to accommodate the lowest and the highest frequency, f_{max} and f_{min} , to be synthesized. A recommended choice for most applications is to choose a tracking half-bandwidth Δf , such that:

$$\Delta f \approx f_{max} - f_{min}$$

If a variable input frequency and a variable counter modulus N is used, then the maximum and the minimum values of output frequency will be:

$$f_{max} = N_{max}(f_S)_{max} \text{ and } f_{min} = N_{min}(f_S)_{min}$$

If a fixed output frequency is desired, i.e. N and f_S are fixed, then a $\pm 10\%$ tracking bandwidth is recommended. Excessively large tracking bandwidth may cause the PLL to lock on the harmonics of the input signals; and the small tracking range increases the "lock-up" or acquisition time.

Design Instructions

For a given performance requirement, the circuit of Figure 12 can be optimized as follows:

- a) Choose center frequency, f_0 , to be equal to the output frequency to be synthesized. If a range of output

frequencies is desired, set f_0 to be at mid-point of the desired range.

- b) Choose timing resistor R_0 to be in the range of 15k Ω to 100k Ω . This choice is arbitrary. R_0 can be fine tuned with a series potentiometer, R_X .
- c) Choose timing capacitor, C_0 from Figure 7 or Equation 1.
- d) Calculate R_1 to set tracking bandwidth (see Figure 10 and design equation 5). If a range of output frequencies are desired, set R_1 to get:

$$\Delta f = f_{max} - f_{min}$$

If a single fixed output frequency is desired, set R_1 to get:

$$\Delta f = 0.1 f_0$$

- e) Calculate C_1 to obtain desired loop damping. (See design equation 4). For most applications, $\zeta = 1/2$ is recommended, thus:

$$C_0 = NC_0/4$$

Note

All component values except R_0 can be rounded off to the nearest standard value.

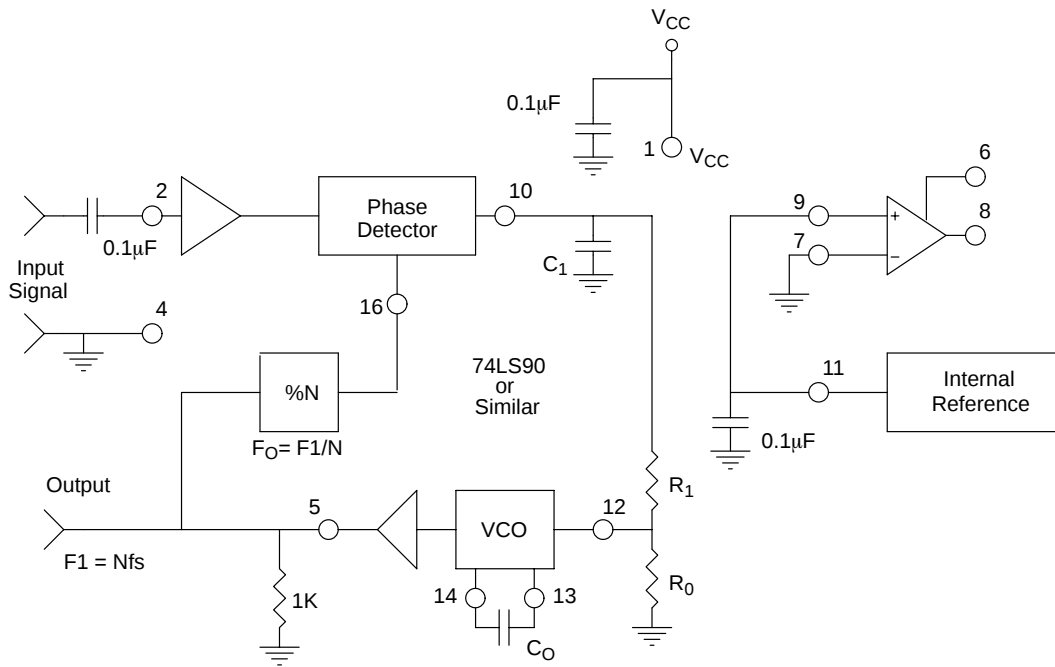


Figure 12. Circuit Connection for Frequency Synthesizer

INPUT SENSITIVITY

The input to the XR-2212 may sometimes be too sensitive to noise conditions on the input line. *Figure 13* illustrates a method of de-sensitizing the XR-2212 from such noisy line conditions by the use of a resistor, R_x , connected from pin 2 to ground. The value of R_x is chosen by the equation and the desired minimum signal threshold level.

V_{IN} minimum (peak) input voltage must exceed this value to be detected (equivalent to adjusting V threshold).

$$V_{IN} \text{ minimum (peak)} = V_a - V_b =$$

$$\Delta V \pm 2.8V \text{ offset} = V_{REF} = \frac{20,000}{(20,000 + R_x)} \text{ or}$$

$$R_x = 20,000 \left(\frac{V_{REF}}{\Delta V} - 1 \right)$$

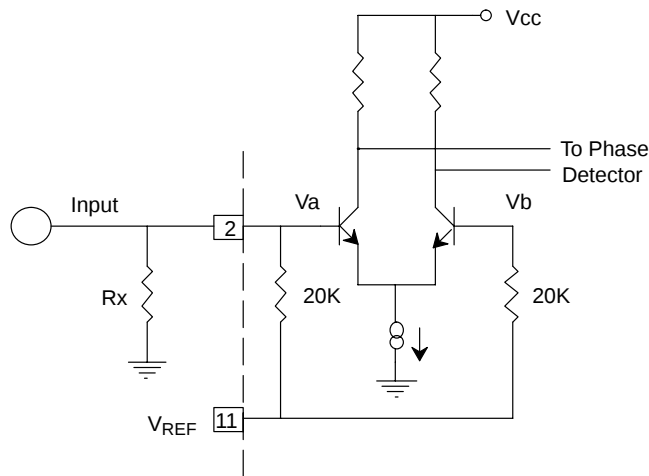
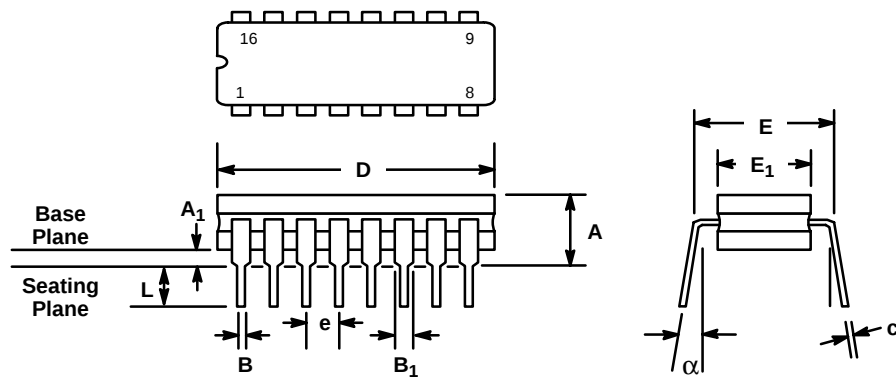


Figure 13. Desensitizing Input Stage

**16 LEAD CERAMIC DUAL-IN-LINE
(300 MIL CDIP)**

Rev. 1.00

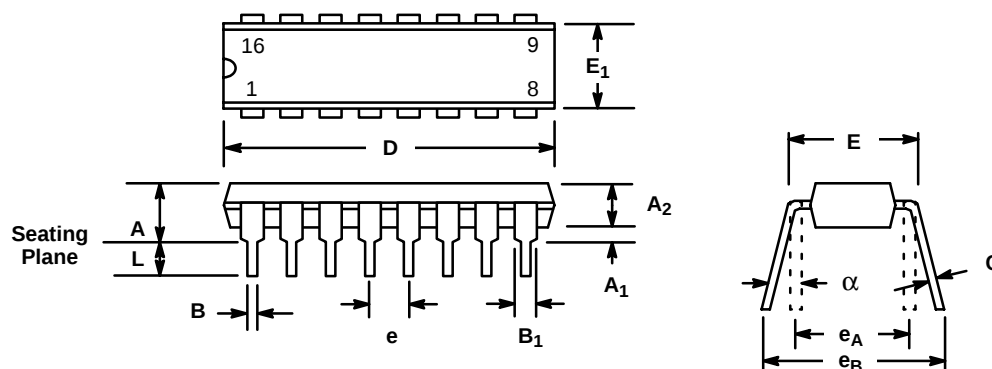


SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.100	0.200	2.54	5.08
A ₁	0.015	0.060	0.38	1.52
B	0.014	0.026	0.36	0.66
B ₁	0.045	0.065	1.14	1.65
c	0.008	0.018	0.20	0.46
D	0.740	0.840	18.80	21.34
E ₁	0.250	0.310	6.35	7.87
E	0.300 BSC		7.62 BSC	
e	0.100 BSC		2.54 BSC	
L	0.125	0.200	3.18	5.08
α	0°	15°	0°	15°

Note: The control dimension is the inch column

16 LEAD PLASTIC DUAL-IN-LINE (300 MIL PDIP)

Rev. 1.00



SYMBOL	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.145	0.210	3.68	5.33
A ₁	0.015	0.070	0.38	1.78
A ₂	0.115	0.195	2.92	4.95
B	0.014	0.024	0.36	0.56
B ₁	0.030	0.070	0.76	1.78
C	0.008	0.014	0.20	0.38
D	0.745	0.840	18.92	21.34
E	0.300	0.325	7.62	8.26
E ₁	0.240	0.280	6.10	7.11
e	0.100 BSC		2.54 BSC	
e _A	0.300 BSC		7.62 BSC	
e _B	0.310	0.430	7.87	10.92
L	0.115	0.160	2.92	4.06
α	0°	15°	0°	15°

Note: The control dimension is the inch column

Notes

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